

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C		
	60mΩ @ V _{GS} = -10V	-4.3A		
-60V	80mΩ @ V _{GS} = -4.5V	-3.7A		

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC converters
- Motors

Pin¹

	SI⊡[()	F
	G1 🖂	F
	sгП	F
	G2 III	
/iew	Top View Pin Configurat	ion

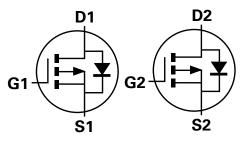
Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP6051SSDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.074 grams (Approximate)



Equivalent Circuit

Ordering Information (Note 4)

Top V

SO-8

Orderable Part Number	Baakaga	Packing		
	Package Qty.		Carrier	
DMP6051SSDQ-13	SO-8	2,500	Tape & Reel	

🗖 D1

🔟 D1

🗖 D2

 $\Box D2$

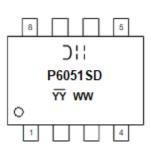
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



See https: Lead-free.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	-60	V	
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 6) V _{GS} = -10V	T _A = +25°C T _A = +70°C	lD	-4.3 -3.4	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-30	А	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	-4.3	A	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)	lsм	-30	A	
Avalanche Current, L = 0.1mH		las	-27.4	A
Avalanche Energy, L = 0.1mH		E _{AS}	37.5	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	PD	1.4	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	86	°C/W
Total Power Dissipation (Note 6)		PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	76	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

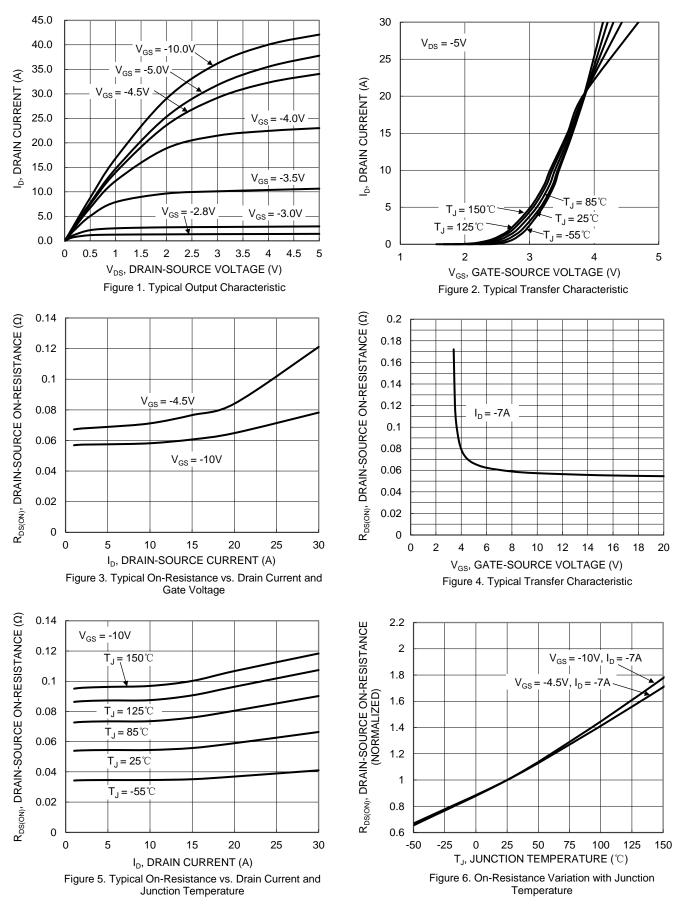
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Symbol	WIIII	тур	WIAA	Onit	Test condition
Drain-Source Breakdown Voltage	BVpss	-60	_	_	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			•		•	·
Gate Threshold Voltage	Vgs(th)	-1	—	-3	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Deserve	_	46	60	mΩ	$V_{GS} = -10V, I_D = -7A$
Static Dialit-Source Off-Resistance	R _{DS(ON)}		58	80	11152	V _{GS} = -4.5V, I _D = -7A
Diode Forward Voltage	Vsd		-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		2079	—	pF	
Output Capacitance	Coss		95	—	pF	VDS = -30V, VGS = 0V, f = 1MHz
Reverse Transfer Capacitance	Crss		78	—	pF	
Gate Resistance	Rg		3.4	—	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = -4.5V)	Qg		17	—	nC	
Total Gate Charge (V _{GS} = -10V)	Qg	_	36	—	nC	Vps = -30V. lp = -5A
Gate-Source Charge	Qgs	_	5.7	—	nC	VDS30V, ID5A
Gate-Drain Charge	Q _{gd}	_	6.7	—	nC	
Turn-On Delay Time	td(on)	_	6.2	—	ns	
Turn-On Rise Time	t _R	_	22	—	ns	V _{DD} = -30V, V _{GS} = -10V,
Turn-Off Delay Time	tD(OFF)	_	39	—	ns	$R_G = 3\Omega$, $I_D = -5A$
Turn-Off Fall Time	tF		24.7	—	ns	
Body Diode Reverse Recovery Time	t _{RR}		24.5	—	ns	I _F = -5A, di/dt = 100A/µs
Body Diode Reverse Recovery Charge	Qrr		23.4	—	nC	$I_{\rm F} = -5A$, $u/ut = 100A/\mu s$

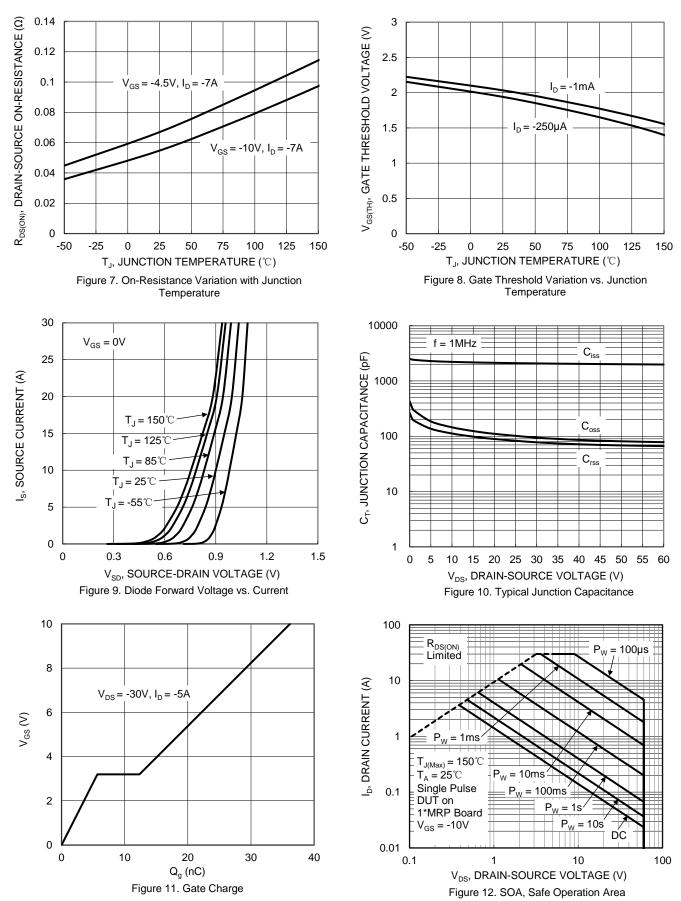
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.

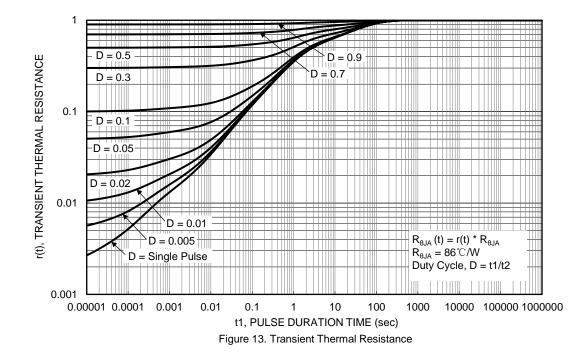








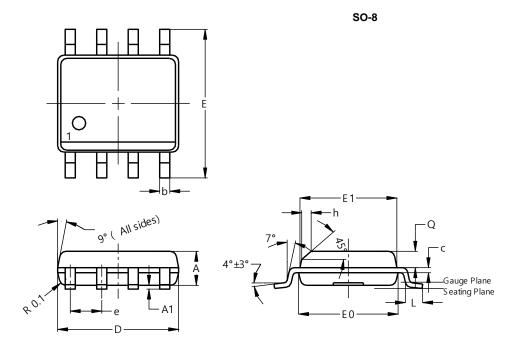






Package Outline Dimensions

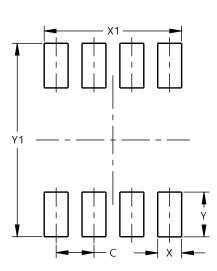
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
с	0.15	0.25	0.20		
D	4.85	4.95	4.90		
ш	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
e			1.27		
h	-		0.35		
1	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Y	1.505			
Y1	6.50			



IMPORTANT NOTICE

1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

Diodes' products provided subiect to Diodes' Standard Terms and Conditions of 5 are Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

9. This Notice may be periodically updated with the most recent version available at https://www.diodes.com/about/company/terms-and-conditions/important-notice

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners. © 2024 Diodes Incorporated. All Rights Reserved.

www.diodes.com